

PFS

SCHOTTKY BARRIER RECTIFIER

SB120 THRU SB1200

VOLTAGE RANGE
CURRENT

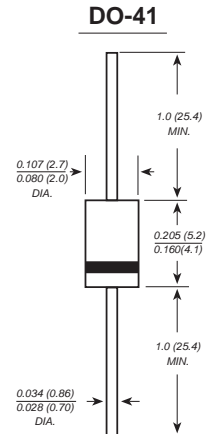
20 to 200 Volts
1.0 Ampere

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guardring for overvoltage protection
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

- Case : R-1 molded plastic body
- Terminals : Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity : Color band denotes cathode end
- Mounting Position : Any
- Weight : 0.007 ounce, 0.20 gramS



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	SB 120	SB 130	SB 140	SB 150	SB 160	SB 170	SB 180	SB 190	SB 1100	SB 1150	SB 1200	UNITS	
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	70	80	90	100	150	200	VOLTS	
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	49	56	63	70	105	140	VOLTS	
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	70	80	90	100	150	200	VOLTS	
Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig.1)	$I_{(AV)}$	1.0											Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	40.0											Amps	
Maximum instantaneous forward voltage at 1.0A	V_F	0.55		0.70		0.85			0.95			Volts		
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	0.5					0.2			2.0				mA
Typical junction capacitance (NOTE 1)	C_J	110			80									pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0											°C/W	
Operating junction temperature range	T_J	-65 to +125					-65 to +150							°C
Storage temperature range	T_{STG}	-65 to +150											°C	

- Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted



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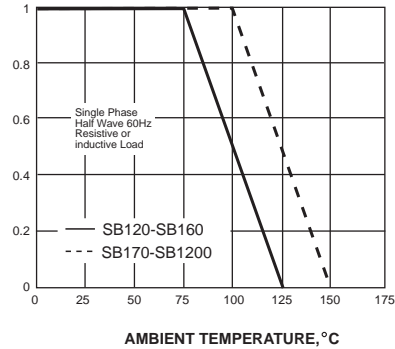
SB120 THRU SB1200

VOLTAGE RANGE
CURRENT

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1.0 Ampere

AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

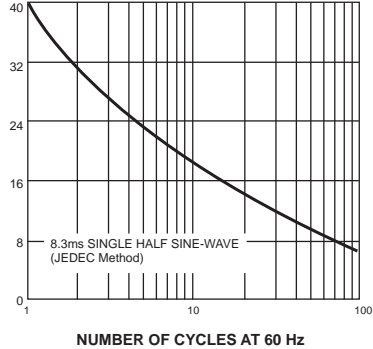


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

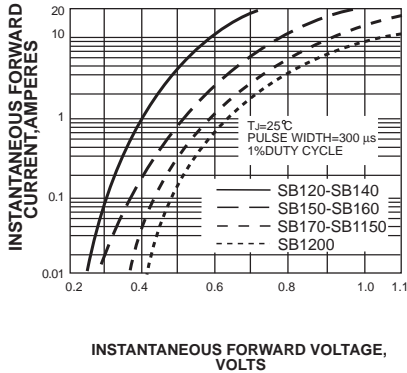


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

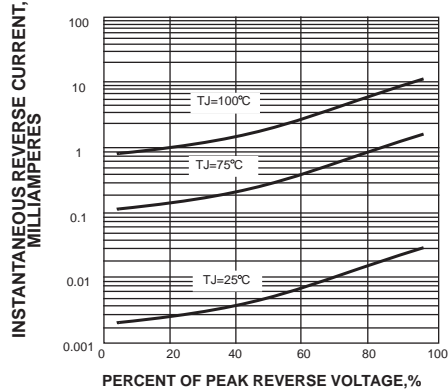
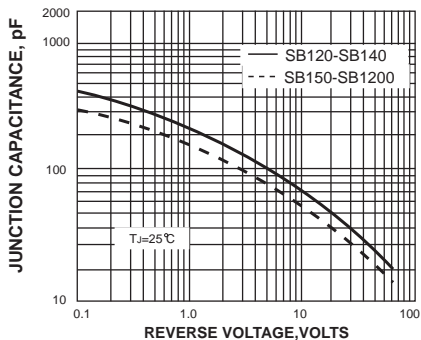


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
 $^{\circ}\text{C}/\text{W}$

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

